

HEAT TRANSFER IN THIN METAL FILM MODELED BY BOLTZMANN TRANSPORT EQUATION AND A TWO-TEMPERATURE MODEL

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Abstract: In the paper a description of heat transfer in a one-dimensional metal films is considered. The Boltzmann transport equation and a two-temperature model supplemented by appropriate boundary and initial conditions are applied to analyze the thermal process in a heated thin metal film. The problem considered is solved by the lattice Boltzmann method and the finite difference method respectively. The internal heat source is given in two different ways. In the first way, the internal heat source is considered a constant value, while in the second way an exponential function which simulates irradiation using a laser pulse is used. In the final part of the paper numerical examples of comparison of two methods and conclusions are presented.

Keywords: Boltzmann transport equation, Two-temperature model, Heat transfer, Lattice Boltzmann method, Finite difference method.

1. Introduction

In metals heat transport is generally realized by two kinds of heat carriers: electrons and quanta of lattice vibrations called phonons. It is important to take into account these both energy carriers when creating mathematical model of this phenomena in the nanoscale. The use of the system of coupled Boltzmann transport equations and the two-temperature model, here proposed, allow to determine the heat exchange in the electron gas and the metal lattice, which is not the case when using the popular Fourier equation.

2. Methods

In the paper the Boltzmann transport equation and two-temperature model are considered. A thin metal film is irradiated by laser. The internal heat source is given in two ways. In the first one, a constant heat source Q(t) = const is considered. The second way takes into account the temporal variation of the laser pulse approximated by a form of exponential function (Lee, 2011).

$$Q(t) = I_0 e^{-\beta t} \tag{1}$$

where I_0 is the peak power intensity of the laser pulse, β is the laser pulse parameter that determines the shape of the pulse.

2.1. The lattice Boltzmann method and the Boltzmann transport equation

The unsteady BTEs transformed into equivalent energy density equations for the 1D coupled model with two kinds of carriers (*e*-electrons and *l*-lattice vibrations called phonons) can be written using the formulas (Escobar, 2006 and Hopkins, 2009):

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$$\frac{\partial e_e(x,t)}{\partial t} + \mathbf{v}_e \cdot \nabla e_e(x,t) = -\frac{e_e(x,t) - e_e^0(x,t)}{\tau_e} + Q_e(x,t)$$
(2)

$$\frac{\partial e_l(x,t)}{\partial t} + \mathbf{v}_l \cdot \nabla e_l(x,t) = -\frac{e_l(x,t) - e_l^0(x,t)}{\tau_l} + Q_l(x,t)$$
(3)

where e_e, e_l are the energy densities, e_e^0, e_l^0 are the equilibrium energies densities, $\mathbf{v}_e, \mathbf{v}_l$ are the frequency-dependent propagation speed, τ_e, τ_l are the relaxation times, *t* denotes the time and Q_e, Q_l are the energies source related to an unit of volume for electrons and lattice respectively.

The electron and phonon energy densities at their equivalent nonequilibrium temperatures are given by the formulas (Escobar, 2006)

$$e_{e}(T_{e}) = \left(n_{e} \frac{\pi^{2}}{2} \frac{k_{b}^{2}}{\varepsilon_{F}}\right) T_{e}^{2}$$

$$\tag{4}$$

$$e_{l}(T_{l}) = \left(\frac{9\eta_{l}k_{b}}{\Theta_{D}^{3}}\int_{0}^{\Theta_{D}/T_{l}}\frac{z^{3}}{\exp(z)-1}dz\right)T_{l}^{4}$$
(5)

where Θ_D is the Debye temperature of the solid, k_b is the Boltzmann constant, T_e , T_l are the temperature for electrons and phonons respectively, while n_e is the electron density and η_{ph} is the phonon density. The electron and phonon energy sources are calculated using the following expressions

$$Q_{e}(x,t) = Q(t) - G(T_{e}(x,t) - T_{ph}(x,t)), \ Q_{ph}(x,t) = G(T_{e}(x,t) - T_{ph}(x,t))$$
(6)

where G is the electron-phonon coupling factor which characterizes the energy exchange between electrons and phonons. Eqs. (2) and (3) should be supplemented by the initial and boundary conditions.

2.2. The finite difference method and a two-temperature model

Two-temperature model describing the temporal and spatial evolution of the lattice and electrons temperatures (T_l and T_e) in the irradiated metal can be written (Chen, 2001) (1D problem)

$$C_e(T_e)\frac{\partial T_e(x,t)}{\partial t} = -\frac{\partial q_e(x,t)}{\partial t} - G[T_e(x,t) - T_l(x,t)] + Q(t)$$
(8)

$$C_{l}\frac{\partial T_{l}(x,t)}{\partial t} = -\frac{\partial q_{l}(x,t)}{\partial t} + G[T_{e}(x,t) - T_{l}(x,t)]$$
(9)

where $T_e(x, t)$, $T_l(x, t)$ are the temperatures of electrons and lattice, respectively, $C_e(T_e)$, C_l are the volumetric specific heats, G is the electron-phonon coupling factor which characterizes the energy exchange between electrons and phonons, Q(t) is the source function associated with the irradiation.

Instead of the classical Fourier law the following formulas are introduced

$$q_e(x,t) + \tau_e \frac{\partial q_e(x,t)}{\partial t} = -\lambda_e(T_e,T_l) \frac{\partial T_e(x,t)}{\partial x}$$
(10)

$$q_{l}(x,t) + \tau_{l} \frac{\partial q_{l}(x,t)}{\partial t} = -\lambda_{l} \frac{\partial T_{l}(x,t)}{\partial x}$$
(11)

where $\lambda_e(T_e, T_l)$, λ_l are the thermal conductivities of electrons and lattice, respectively, τ_e is the relaxation time of free electrons in metals, τ_l is the relaxation time in phonon collisions.

For low laser intensity the following relationships describing the electrons thermal capacity and volumetric specific heat are widely used (Chen, 2001 and Lin, 2008)

$$\lambda_e(T_e, T_l) = \lambda_0 \frac{T_e}{T_l}, \ C_e(T_e) = AT_e$$
(12)

where λ_0 and *A* are the material constants (Majchrzak, 2012). For low laser intensity λ_l , C_l , and *G* are also constant values depended on material.

To solve the problem formulated the algorithm basing on the finite difference method is used (Majchrzak, 2012). A staggered grid is introduced in which the temperature nodes i = 0, 2, 4, ..., N and the heat fluxes nodes j = 1, 3, ..., N-1 are introduced. It means that $T_i^f = T(ih, f\Delta t)$ and $q_j^f = q(jh, f\Delta t)$, where *h* is the mesh size, Δt is the time step f = 0, 1, 2, ..., F.

3. Results of computations

As a numerical example the heat transport in a gold thin film of the thickness L = 100 nm has been analysed. The following input data have been introduced: the relaxation times $\tau_e = 0.04 \text{ ps}$, $\tau_{ph} = 0.8 \text{ ps}$, the Debye temperature $\Theta_D = 170 \text{ K}$, the peak power intensity of the laser pulse $I_0 = 2 \cdot 10^{13} \text{ W/m}^2$, the coupling factor $G = 2.3 \cdot 10^{16} \text{ W/m}^3 \text{K}$, the boundary conditions of the 2nd type on the both edges $q_{b1}^k(0, t) = q_{b2}^k(L, t) = 0$, the initial temperature $T_0 = 300 \text{ K}$. The lattice step $\Delta x = 1 \text{ nm}$ and the time step $\Delta t = 0.001 \text{ ps}$ have been assumed. Three values of the laser pulse parameter β was taken into account: 1) $0.5.10^{13} \text{ s}^{-1}$; 2) 10^{13} s^{-1} ; 3) $1.5.10^{13} \text{ s}^{-1}$ (see Fig. 1b).



Fig. 1: Heating curves for x = 0: a) Q(t) = const; b) $Q(t) = I_0 e^{-\beta t}$.

time	FDM	LBM	δ [%]	time	FDM	LBM	δ [%]
0.04	440.0907	438.3789	0.38897	0.24	582.5611	580.8897	0.28691
0.08	508.7353	506.5825	0.42317	0.28	582.7515	581.5039	0.21409
0.12	546.5965	544.3312	0.41444	0.32	580.2610	579.5346	0.12519
0.16	567.5201	565.3244	0.38689	0.36	576.0237	575.9115	0.01948
0.2	578.2466	576.2557	0.3443	0.4	570.6550	571.2458	0.1035

Tab. 1: Comparison of temperatures in node x=0, $\beta=10^{13} s^{-1}$.

In Figs. 1a and 1b heating curves obtained using Boltzmann transport equation (continuous line) and two temperature model (triangles) is shown. The consistency of the results is very high. Tab. 1 presents estimated error between these two methods. In Fig. 2 the distributions of heat source function for three different values of β : 1) 0.5.10¹³ s⁻¹; 2) 10¹³ s⁻¹; 3) 1.5.10¹³ s⁻¹ are presented.

To compare the results of the two presented approaches the relative error δ is defined (see Tab. 1)

$$\delta = \left| \frac{\mathbf{FDM} - \mathbf{LBM}}{\mathbf{FDM}} \right| \cdot 100\% \tag{13}$$



Fig. 2: Heat source function.

4. Conclusions

In the paper the temperatures obtained using two different mathematical models: the Boltzmann transport equation and the two-temperature model were compared. Numerical methods: the lattice Boltzmann method and the finite difference method respectively were used to solve them. The results obtained when applying the two types of heat sources are comparable.

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